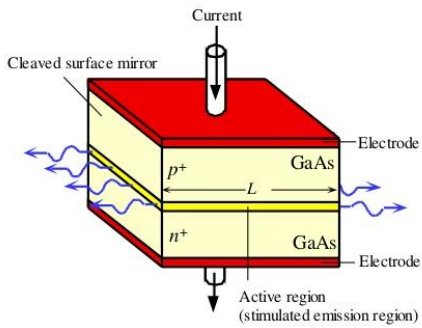


# Measurement of the Linewidth broadening factor



# Linewidth broadening factor (LBF)

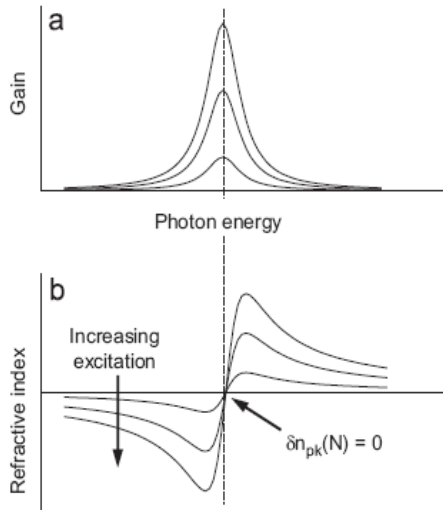


□ Linewidth broadening factor, or  $\alpha$ -factor, describes the coupling between the carrier-induced variation of real and imaginary parts of the optical susceptibility.

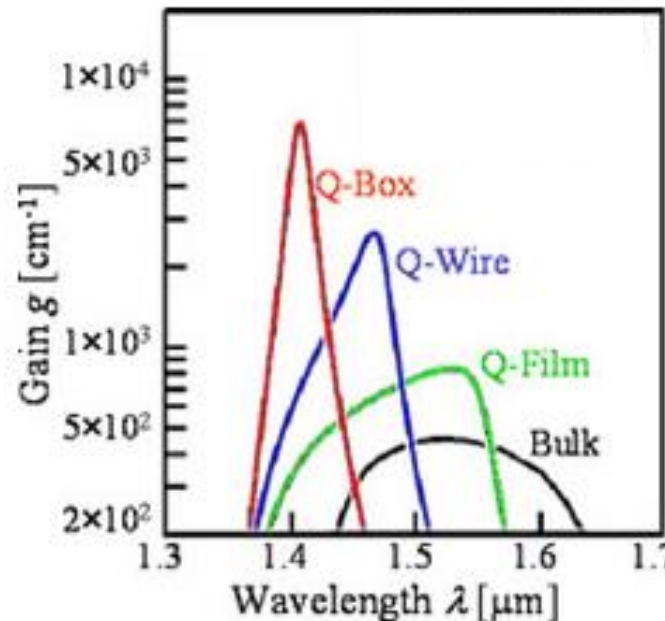
*C. H. Henry, JQE QE-18, 259, 1982*

$$\alpha_H = \frac{\partial \text{Re}\{\chi\} / \partial N}{\partial \text{Im}\{\chi\} / \partial N}$$

→ Refractive index  
→ Optical gain



Kramer-Kronig relation



Zero  $\alpha$ -factor value was expected in Qdot lasers!

*M. Asada et al. JQE QE-22, 1915, 1986*

- Spectral linewidth broadening

*C. H. Henry, JQE QE-18, 259, (1982)*

$$\Delta\nu \propto (1 + \alpha_H^2)$$

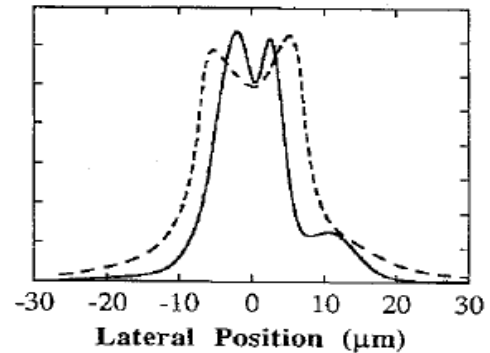
- Chirp under direct modulation

*L. A. Coldren, Diode Lasers and..., Wiley, 1995*

$$\Delta f \propto \alpha_H$$

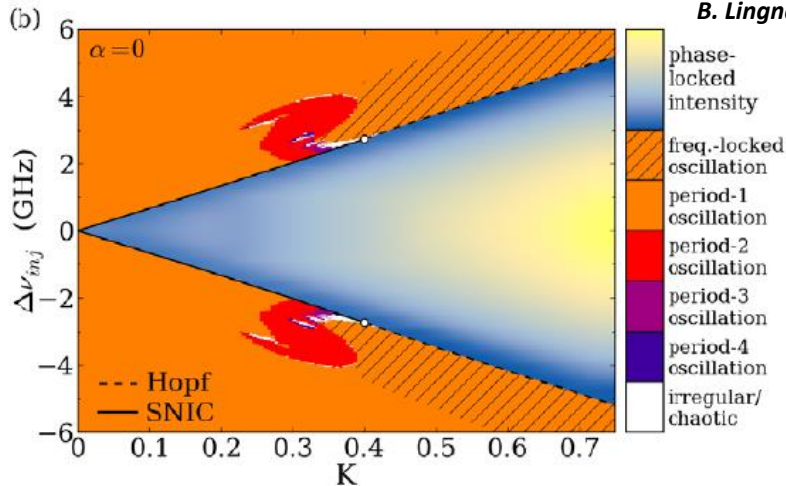
- Laser beam filamentation

*J. R. Marciante, G. P. Agrawal. JQE32, 590 (1996)*



- Optical injection/feedback dynamics

*B. Lingnau, et al. NJP15, 093031 (2013)*



□ The definition of the LBF is equivalent to

$$\alpha_H = - \frac{4\pi}{\lambda} \frac{dn / dN}{dg / dN}$$

□ Assume the gain  $g$  and the refractive index  $n$  have a linear dependence with the carrier density  $N$  (i. e. no gain compression)

$$\alpha_H = - \frac{4\pi}{\lambda} \frac{\Delta n}{\Delta g}$$

□ The equivalent forms are

$$\begin{aligned} \frac{c}{n} &= \lambda v \Rightarrow \\ \frac{\Delta n}{n} &= \frac{\Delta \lambda}{\lambda} \\ \frac{\Delta n}{n} &= - \frac{\Delta v}{v} \Rightarrow \\ \alpha_H &= - \frac{4\pi}{\lambda^2} \frac{n \Delta \lambda}{\Delta g} \end{aligned}$$

□ The mode spacing

$$\begin{aligned} D_v &= \frac{c}{2nL} \Rightarrow \\ \frac{D_v}{v} &= \frac{D_\lambda}{\lambda} \Rightarrow \\ D_\lambda &= \frac{\lambda}{v} D_v = \frac{\lambda}{v} \frac{c}{2nL} = \frac{\lambda^2}{2nL} \end{aligned}$$



- The LBF

$$\alpha_H = -\frac{2\pi}{LD_\lambda} \frac{\Delta\lambda}{\Delta g}$$

- Here the wavelength and the gain are varied by changing the bias current

$$\alpha_H = -\frac{2\pi}{LD_\lambda} \frac{\Delta\lambda / \Delta I}{\Delta g_{net} / \Delta I}$$

with

$$g_{net} = g - \alpha_i$$

$$g_{net}^{th} = \alpha_m \\ = \frac{1}{2L} \ln \frac{1}{R_1 R_2}$$

- The net modal gain is extracted from the peak-to-valley ratio of the amplified spontaneous spectrum

$$g_{net} = \frac{1}{L} \ln \left( \frac{1}{R} \frac{\sqrt{r} - 1}{\sqrt{r} + 1} \right)$$

with

$$r = P_{\max} / P_{\min}$$

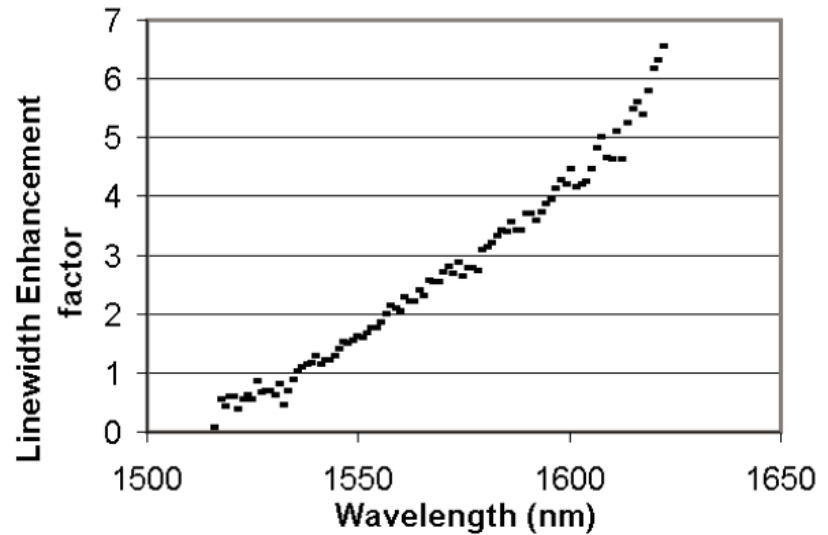
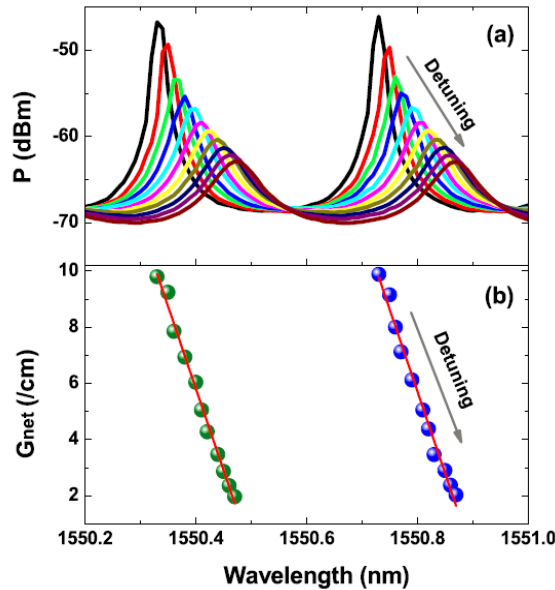
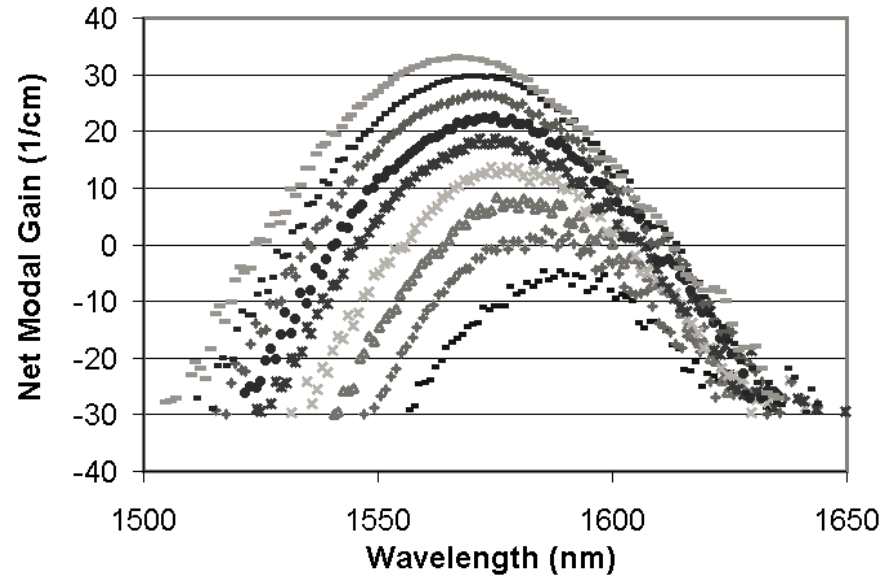
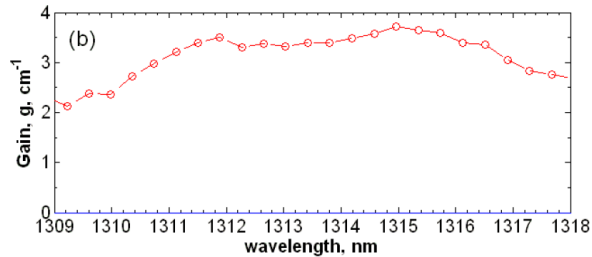
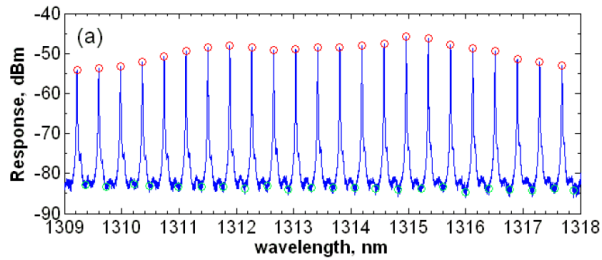
- The optical power

$$(dBm) = 10 \log_{10}(mW)$$

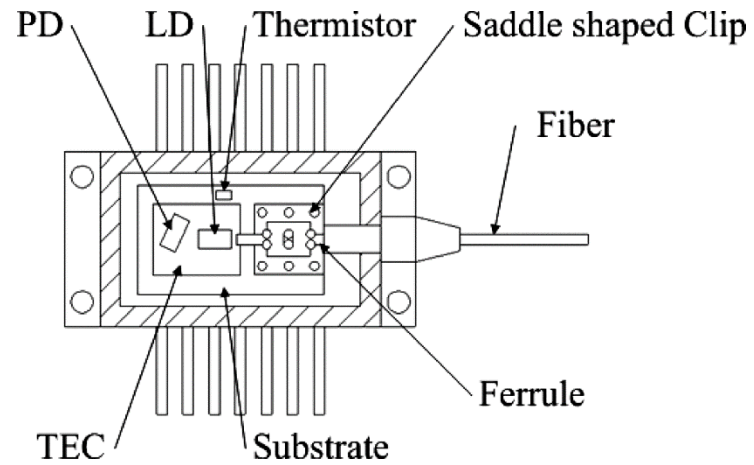
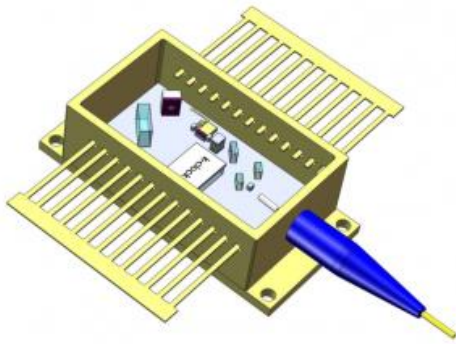
- The wavelength change is directly obtained from the optical spectrum



# Hakki-Paoli method



# Laser device under test



□ The device under study is a quantum well Fabry-Perot laser, lasing around 1550 nm. The refractive index is 3.5, and the facet reflectivity is 0.32.

## 1. L-I curve measurement

- a) Measure the L-I curves from 0 mA to 80 mA (step 2 mA) at 15°, 20°, and 30°, and plot it
- b) From the L-I plot, extract the lasing threshold  $I_{th}$ .

## 2. Optical spectrum measurement

Condition: Set the temperature at 20°, the bias current at the threshold, adjust the spectrum peak to the middle of the screen, set the span at 20 nm, set the resolution at 0.02 nm.

- a) Measure the optical spectrum at the lasing threshold, and plot it
- b) From the spectrum, extract the mode spacing both in wavelength  $D_x$  and in frequency  $D_v$ , and then calculate the cavity length.





## 3. Net gain measurement

- 1) Following the conditions in 2., measure the optical spectra from  $(I_{th}-10)$  mA to  $(I_{th}+10)$  mA, with a step of 0.5 mA.
- 2) Extract the net gain from the optical spectra for each bias current, and plot it (**gain clamping**)
- 3) Below threshold, plot  $dg_{net}/dI$  as a function of the wavelength in the 20-nm span
- 4) Below threshold, plot  $(d\lambda/dI)_{below}$ , which is due to both carrier change (**blue shift**) and thermal effect (**red shift**).
- 5) Above threshold, plot  $(d\lambda/dI)_{above}$ , which is due to only the thermal effect
- 6) Below threshold, the carrier induced wavelength shift is obtained by

$$d\lambda/dI = (d\lambda/dI)_{below} - (d\lambda/dI)_{above}$$

- 7) Plot the linewidth broadening factor as a function of the wavelength

$$\alpha_H = -\frac{2\pi}{LD_\lambda} \frac{d\lambda/dI}{dg_{net}/dI}$$

